8-Bit Shift and Store **Register with LSTTL Compatible Inputs**

High-Performance Silicon-Gate CMOS

The MC74HCT4094A is a high speed CMOS 8-bit serial shift and storage register. This device consists of an 8-bit shift register and latch with 3-state output buffers. Data is shifted on positive clock (CP) transitions. The data in the shift register is transferred to the storage register when the Strobe (STR) input is high. The output buffers are enabled when the Output Enable (OE) input is set high. Two serial outputs (QS₁, QS₂) are available for cascading multiple devices.

The MC74HCT4094A can be used to interface TTL or CMOS outputs to high speed CMOS inputs.

Features

- Wide Operating Voltage Range: 4.5 to 5.5 V
- Low Power Dissipation: $I_{CC} = < 10 \,\mu\text{A}$
- THIS DEVICE PLEASENTATIVE PREPRESENTATIVE PROBLEMANTATIVE PROB • In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- These are Pb-Free Devices

Typical Applications

- Serial-to-Parallel Conversion
- Remote Control Storage Register



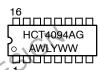
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MARKING DIAGRAMS

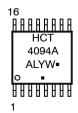


SOIC-16 D SUFFIX CASE 751B





DT SUFFIX



Assembly Location

= Wafer Lot = Year WW, W = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

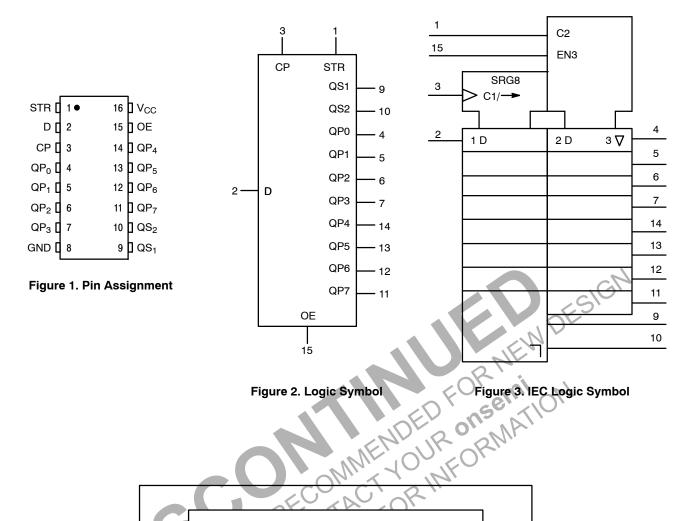


Figure 2. Logic Symbol

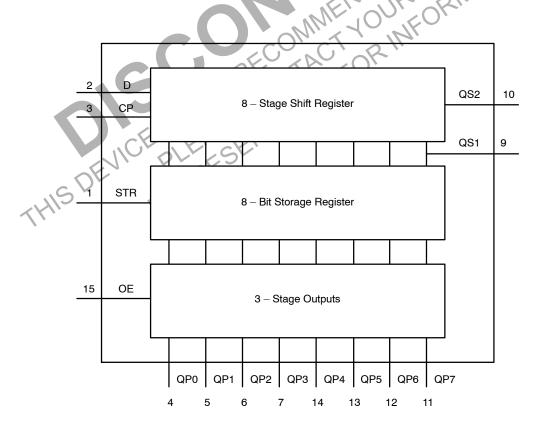
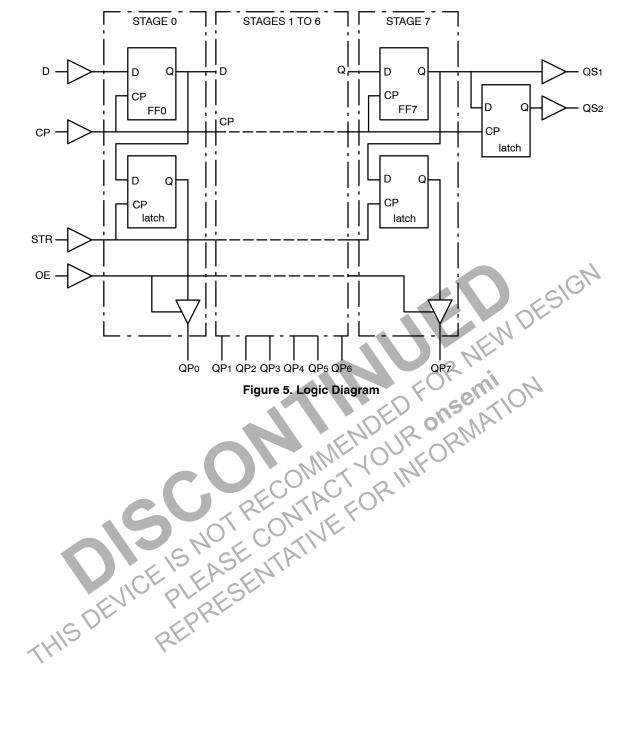


Figure 4. Functional Diagram



MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V _{in}	DC Input Voltage (Referenced to GND)	- 0.5 to V _{CC} + 0.5	V
V _{out}	DC Output Voltage (Referenced to GND)	- 0.5 to V _{CC} + 0.5	V
I _{in}	DC Input Current, per Pin	± 20	mA
I _{out}	DC Output Current, per Pin	± 35	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins	± 75	mA
P _D	Power Dissipation in Still Air, SOIC Package† TSSOP Package†	500 450	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and Vout should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

T _{stg}	Storage Temperature	– 65 to	+ 150	°C	Unused outputs must be left open.
ratings only Extended e reliability. †Derating	xceeding Maximum Ratings may damage the device. In y. Functional operation above the Recommended Operators exposure to stresses above the Recommended Operating - SOIC Package: - 7 mW/°C from 65° to 125°C TSSOP Package: - 6.1 mW/°C from 65° to 125°C	ting Conditi	ons is not	implied.	
Symbol	Parameter	Min	Max	Unit	NEV
V _{CC}	DC Supply Voltage (Referenced to GND)	4.5	5.5	V	P'ai
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	V	nsemi ON
T _A	Operating Temperature, All Package Types	- 55	+125	°CC	SMY
t _r , t _f	Input Rise and Fall Time (Figure 1)	0	500	ns	Dr.
~	Input Rise and Fall Time (Figure 1)	TAC	FOR		

FUNCTIONAL TABLE

INPUTS			PARALLEL OUTPUTS		SERIAL OUTPUTS		
СР	OE	STR	D	QP0	QPn	QS1	QS2
1	L	Х	Х	Z	Z	Q'6	NC
\downarrow	L	Х	Х	Z	Z	NC	QP7
1	Н	L	Х	NC	NC	Q'6	NC
1	Н	Н	L	L	QPn-1	Q'6	NC
1	Н	Н	Н	Н	QPn-1	Q'6	NC
\downarrow	Н	Н	Н	NC	NC	NC	QP7

Notes

- 1. H = HIGH voltage level
 - L = LOW voltage level
 - X = don't care
 - Z = high impedance OFF-state

 - NC = no change

 ↑ = LOW-to-HIGH CP transition

 ↓ = HIGH-to-LOW CP transition

Q'6 = the information in the seventh register stage is transferred to the 8th register stage and QSn output at the positive clock edge

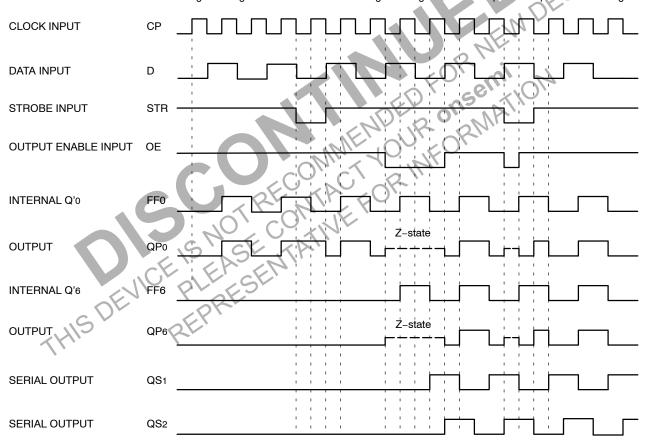


Figure 6. Timing Diagram

DC CHARACTERISTICS

				Guar	anteed Limit	s	
Symbol	Parameter	Test Conditions	V _{CC} (V)	-55°C to 25°C	≤ 85°C	≤ 125°C	Unit
V _{IH}	Minimum High-Level Input	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	4.5	2.0	2.0	2.0	V
	Voltage	J _{OUT} ≤ 20 μA	5.5	2.0	2.0	2.0	
V_{IL}	Maximum Low-Level Input	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$	4.5	0.8	0.8	0.8	V
	Voltage	I _{OUT} ≤ 20 μA	5.5	0.8	0.8	0.8	
V _{OH}	Minimum High-Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL}$	4.5	4.4	4.4	4.4	V
	Voltage	I _{OUT} ≤ 20 μA	5.5	5.4	5.4	5.4	
		$V_{IN} = V_{IH}$ or V_{IL} , $ _{OUT} = 6$ mA	4.5	4.25	4.2	4.1	
V _{OL}	Maximum Low-Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL}, \mid I_{OUT} \mid \leq 20 \mu A$	4.5	0.1	0.1	0.1	V
	Voltage		5.5	0.1	0.1	0.1	
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} = 6 mA	4.5	0.25	0.3	0.4	
I _{IN}	Maximum Input Leakage Current	V _{IN} = V _{CC} or GND	5.5	±0.1	±1	S/(A)	μА
I _{OZ}	Maximum Tri-State Output Leakage Current	$V_{IN} = V_{CC}$ or GND $V_{OUT} = V_{CC}$ or GND	5.5	±0.5	(1±5)	±10	μА
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5	4.0	40	80	μΑ
	<u> </u>			£0, 4	11 11		+
ΔI_{CC}	Additional Quiescent Supply Current	V _{in} = 2.4V, Any One Input V _{in} = V _{CC} or GND, Other Inputs		≥ -55° C	25 to	125°C	_

mΑ

AC CHARACTERISTICS ($t_f = t_r = 6 \text{ ns}, C_L = 50 \text{ pF}$)

				Guai	anteed Limit	s	
Symbol	Parameter	Test Conditions	V _{CC} (V)	-55°C to 25°C	≤ 85°C	≤ 125°C	Unit
t _{PHL} , t _{PLH}	Maximum Propagation Delay CP to QS ₁	Figure 7	4.5	30	38	45	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay CP to QS ₂	Figure 7	4.5	27	34	41	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay CP to QP _n	Figure 7	4.5	39	49	59	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay STR to QP _n	Figure 8	4.5	36	45	54	ns
t _{PZH} , t _{PZL}	Maximum 3-State Output Enable Time OE to QP _n	Figure 9	4.5	35	44	53	ns
t _{PHZ} , t _{PLZ}	Maximum 3-State Output Enable Time OE to QP _n	Figure 9	4.5	25	31	38	ns
t _{THL} , t _{TLH}	Maximum Output Transition Time	Figure 7	4.5	18	22	25	ns
t _W	Minimum Clock Pulse Width High or Low	Figure 7	4.5	16	20	24	ns
t _W	Minimum Strobe Pulse Width High	Figure 8	4.5	16	20	24	ns
t _{SU}	Minimum Set-up Time D to CP	Figure 10	4.5	C010	13	15	ns
t _{SU}	Minimum Set-up Time CP to STR	Figure 8	4.5	205	25	30	ns
t _h	Minimum Hold Time D to CP	Figure 10	4.5	5 35 M	3	3	ns
t _h	Minimum Hold Time CP to STR	Figure 8	4.5	7/ 0	0	0	ns
f _{MAX}	Minimum Clock Pulse Frequency	Figure 7	4.5	30	24	20	MHz
C _{in}	Maximum Input Capacitance	.OP IE	-	10	10	10	pF
C _{out}	Maximum Output Capacitance	2.714	-	15	15	15	pF
C _{PD}	Power Dissipation Capacitance (Note 2)	Th	_	140	140	140	pF

C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I_{CC}(operating) ≈ C_{PD} x V_{CC} x f_{IN} x N_{SW} where N_{SW} = total number of outputs switching and f_{IN} = switching frequency.

AC WAVEFORMS

 $(V_{M} = 1.3 V)$

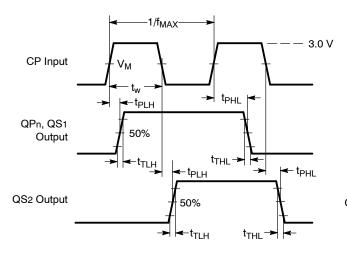
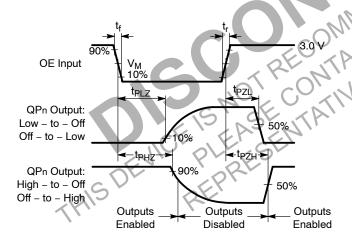
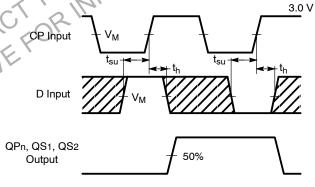


Figure 7. Waveforms showing the clock (CP) to output (QPn, QS1, QS2) propagation delays, the clock pulse width and the maximum clock frequency.

Figure 8. Waveforms showing the strobe (STR) to output (QPn) propagation delays, the strobe pulse width, the clock set-up and hold times for the strobe input.



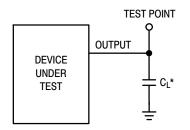


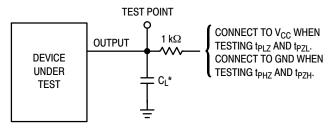
The shaded areas indicate when the input is permitted to change for predictable output performance.

Figure 9. Waveforms showing the 3-state enable and disable times for input OE.

Figure 10. Waveforms showing the data set-up and hold times for the data input.

TEST CIRCUITS





*Includes all probe and jig capacitance

Figure 11. AC Characteristics Load Circuits

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74HCT4094ADG	SOIC-16 (Pb-Free)	48 Units / Rail
MC74HCT4094ADR2G	SOIC-16 (Pb-Free)	2500 Tape & Reel
MC74HCT4094ADT	TSSOP-16*	96 Units / Rail
MC74HCT4094ADTR2G	TSSOP-16*	2500 Tape & Reel
†For information on tape and reel specifications, i Specifications Brochure, BRD8011/D. *This package is inherently Pb–Free.	RECONNER POUR SENTATIVE FOR INT	ORMA TOPO UTO TOPO TOPO TOPO TOPO TOPO TOPO

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}Includes all probe and jig capacitance

^{*}This package is inherently Pb-Free.



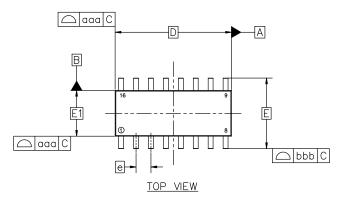


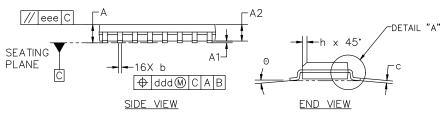
SOIC-16 9.90x3.90x1.50 1.27P CASE 751B ISSUE L

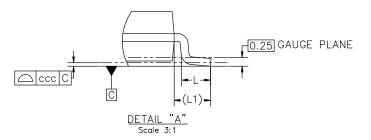
DATE 29 MAY 2024

NOTES:

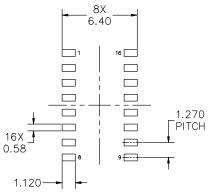
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
- 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE 6 DIMENSION AT MAXIMUM MATERIAL CONDITION.







MILLIMETERS						
DIM	MIN	MAX				
А	1.35	1.55	1.75			
A1	0.00	0.05	0.10			
A2	1.35	1.50	1.65			
b	0.35	0.42	0.49			
С	0.19	0.22	0.25			
D		9.90 BSC				
E		6.00 BSC				
E1	3.90 BSC					
е		1.27 BSC				
h	0.25		0.50			
L	0.40	0.83	1.25			
L1		1.05 REF				
Θ	0.		7*			
TOLERAN	CE OF FC	RM AND	POSITION			
aaa	0.10					
bbb	0.20					
ccc	0.10					
ddd		0.25				
eee		0.10				



RECOMMENDED MOUNTING FOOTPRINT

*FOR ADDITIONAL INFORMATION ON OUR
PB-FREE STRATEGY AND SOLDERING DETAILS,
PLEASE DOWNLOAD THE onsemi SOLDERING
AND MOUNTING TECHNIQUES REFERENCE
MANUAL, SOLDERRM/D

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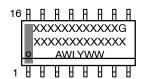
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SOIC-16 9.90x3.90x1.50 1.27P CASE 751B ISSUE L

DATE 29 MAY 2024

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot
 Y = Year
 WW = Work Week
 G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

077/15/		077/15.0		071/15 0		T	
STYLE 1: PIN 1.	COLLECTOR	STYLE 2:	CATHODE	STYLE 3: PIN 1.		TYLE 4: PIN 1.	COLLECTOR DVF #1
PIN 1. 2.		PIN 1. 2.		PIN 1. 2.	COLLECTOR, DYE #1 BASE, #1	2.	
2. 3.	EMITTER	2. 3.	NO CONNECTION				
				3.		3.	
4.	NO CONNECTION	4.		4.		4.	
5.	EMITTER	5.		5.		5.	
6.	BASE	6.		6.		6.	
7.		7.			EMITTER, #2		COLLECTOR, #4
8.		8.		8.			COLLECTOR, #4
9.		9.			COLLECTOR, #3		BASE, #4
10.			ANODE		BASE, #3		EMITTER, #4
	NO CONNECTION	11.			EMITTER, #3		BASE, #3
	EMITTER		CATHODE		COLLECTOR, #3		EMITTER, #3
	BASE		CATHODE		COLLECTOR, #4		BASE, #2
	COLLECTOR	14.			BASE, #4		EMITTER, #2
15.			ANODE		EMITTER, #4		BASE, #1
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1
STYLE 5:		STYLE 6:		STYLE 7:			
STYLE 5: PIN 1.	DRAIN, DYE #1	STYLE 6: PIN 1.	CATHODE	STYLE 7: PIN 1.	SOURCE N-CH		
	DRAIN, DYE #1 DRAIN, #1			PIN 1.	SOURCE N-CH COMMON DRAIN (OUTPUT)		
PIN 1.	,	PIN 1.	CATHODE	PIN 1.	COMMON DRAIN (OUTPUT)		
PIN 1. 2.	DRAIN, #1	PIN 1. 2.	CATHODE CATHODE	PIN 1. 2.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3.	DRAIN, #1 DRAIN, #2	PIN 1. 2. 3.	CATHODE CATHODE	PIN 1. 2. 3.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT)		
PIN 1. 2. 3. 4.	DRAIN, #1 DRAIN, #2 DRAIN, #2	PIN 1. 2. 3. 4.	CATHODE CATHODE CATHODE CATHODE	PIN 1. 2. 3. 4.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT)		
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PIN 1. 2. 3. 4. 5. 6. 7.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4	PIN 1. 2. 3. 4. 5. 6. 7.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH		
PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4 SOURCE, #4	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT)		
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PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10.	DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 GATE, #4 SOURCE, #4 GATE, #3 SOURCE, #3 GATE, #2	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE ANODE ANODE ANODE ANODE ANODE ANODE ANODE	PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10.	COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GATE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) COMMON DRAIN (OUTPUT) GOMMON DRAIN (OUTPUT) GATE N-CH		
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DESCRIPTION:	SOIC-16 9.90X3.90X1.50 1	.27P	PAGE 2 OF 2	

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2X L/2

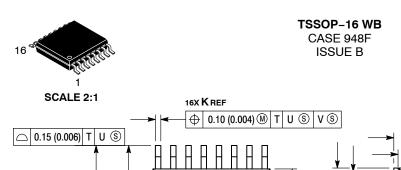
L

☐ 0.15 (0.006)

PIN 1 IDENT.

υ®





DATE 19 OCT 2006

NOTES

Κ

SECTION N-N

0.25 (0.010)

J1

В

-U-

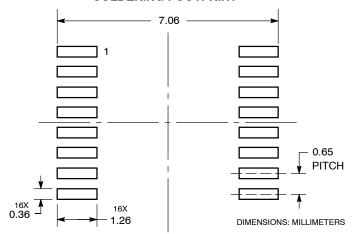
- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
 INTERLEAD FLASH OR PROTRUSION.
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
 NOT EXCEED 0.25 (0.010) PER SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABILE DAMBAR
 PROTRUSION SHALL BE 0.08 (0.003) TOTAL
 IN EXCESS OF THE K DIMENSION AT
 MAXIMUM MATERIAL CONDITION.
 TERMINIAL NILMBERS ADE SUCIUMI ECIP.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.18	0.28	0.007	0.011
7	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40	BSC	0.252 BSC	
М	00	00	00	00

DETAIL E -W-☐ 0.10 (0.004) **DETAIL E** SEATING PLANE D

RECOMMENDED SOLDERING FOOTPRINT*

-V-



^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



= Specific Device Code XXXX Α = Assembly Location

= Wafer Lot L = Year W = Work Week G or • = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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